

Features :

- Interdigitated amplifying gates
- Fast turn-on and high di/dt
- Low switching losses
- Short turn-off time
- Hermetic metal cases with ceramic insulators

$I_{T(AV)}$ **1110A**
 V_{DRM}/V_{RRM} **800~1200V**
 t_q **10~20μs**
 I_{TSM} **11kA**

Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters
- AC motor speed control
- General power switching applications



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^\circ C)$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled,	$T_c=55^\circ C$	125			1110 A
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	tp=10ms		125	800		1200 V
I_{DRM} I_{RRM}	Repetitive peak off-state current Repetitive peak reverse current	at V_{DRM} at V_{RRM}		125			60 mA
$I_{T/f}$	High frequency on-state current	$F=10KHz, T_c=55^\circ C$					500 A
I_{TSM}	Surge on-state current	10ms half sine wave $V_R=0.6V_{RRM}$	125				11 kA
I^{2t}	I^{2t} for fusing coordination						605 A^2s*10^3
V_{TO}	Threshold voltage		125				1.41 V
r_T	On-state slope resistance						0.45 mΩ
V_{TM}	Peak on-state voltage	$I_{TM}=2400A, F=21kN$	125				2.49 V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$	125				200 V/μs
di/dt	Critical rate of rise of on-state current	$V_{DM}= 67\%V_{DRM} \text{ to } 1800A,$ Gate pulse $t_r \leq 0.5\mu s$ $I_{GM}=1.5A$	125				1500 A/μs
Q_{rr}	Recovery charge	$I_{TM}=1000A, tp=2000\mu s,$ $di/dt=-60A/\mu s, V_R=50V$	125		63		μC
t_q	Circuit commutated turn-off time	$I_{TM}=1000A, tp=2000\mu s, V_R=50V$ $dv/dt=30V/\mu s, di/dt=-60A/\mu s$	125	10		20	μs
I_{GT}	Gate trigger current	$V_A=12V, I_A=1A$	25				mA
V_{GT}	Gate trigger voltage			0.8		3.0	V
I_H	Holding current			20		400	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.3			V
$R_{th(j-c)}$	Thermal resistance Junction to case	DC double side cooled Clamping force 21kN				0.024	°C/W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.006	
F_m	Mounting force				18		25 kN
T_{stg}	Stored temperature			-40		140	°C
W_t	Weight				380		g
Outline		P10					

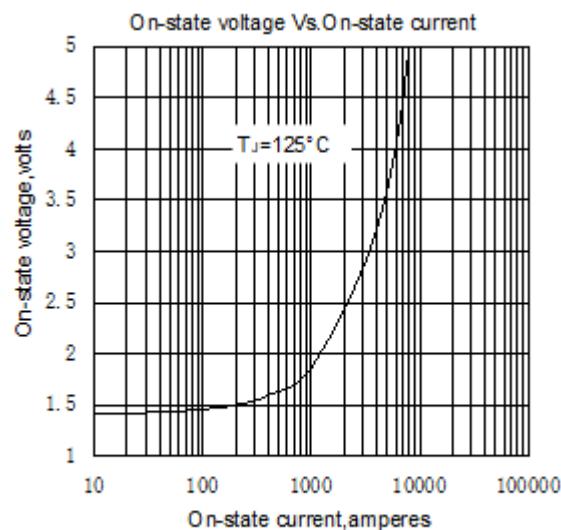


Fig.1

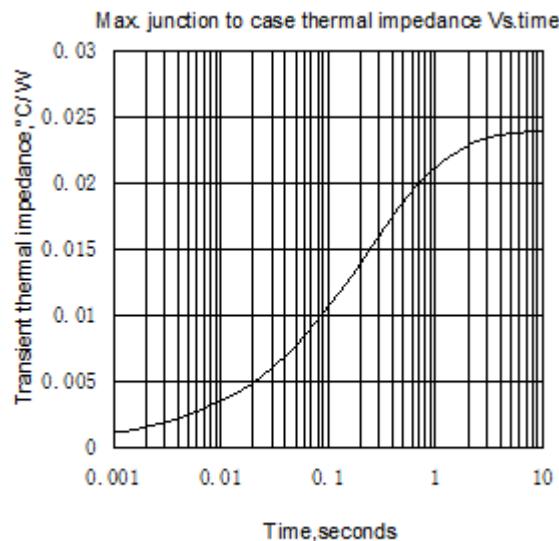


Fig.2

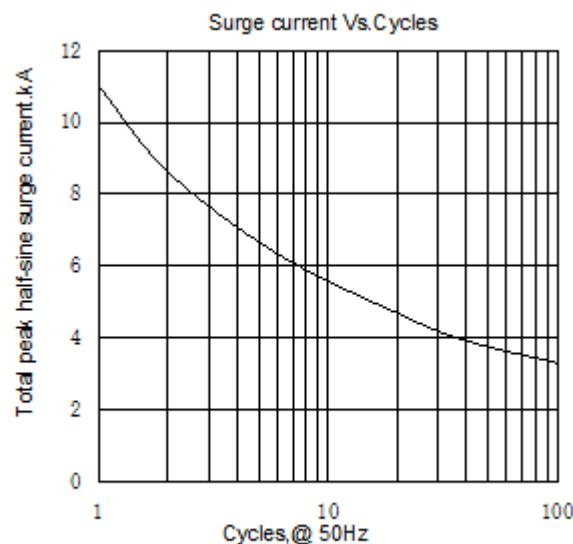


Fig.3

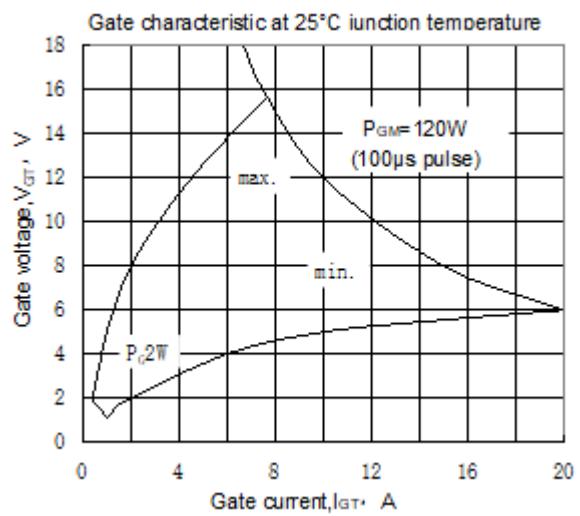


Fig.4

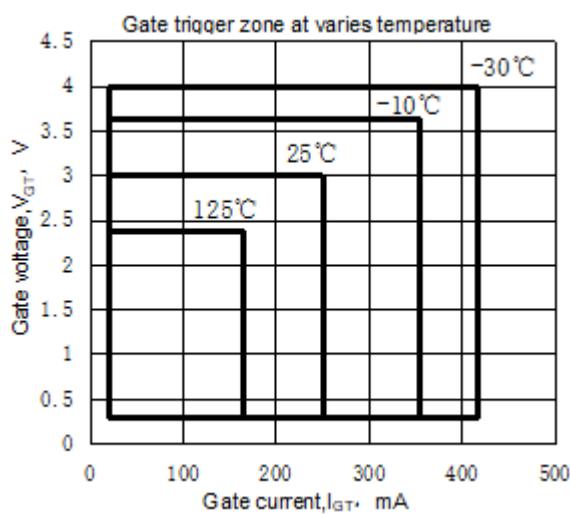


Fig.5

